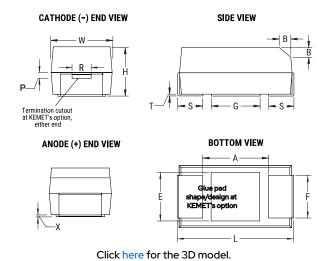


## T495B685M016ATE1K2

T495, Tantalum, MnO2 Tantalum, 6.8 uF, 20%, 16 VDC, SMD, MnO2, Molded, Low ESR, 1.2 Ohms, 3528, 2.1 mm





General Information	
Series	T495
Dielectric	MnO2 Tantalum
Style	SMD Chip
Description	SMD, MnO2, Molded, Low ESR
Features	Low ESR
RoHS	Yes
Termination	Tin
AEC-Q200	No
Typical Component Weight	107.45 mg
Shelf Life	156 Weeks
MSL	1

Dimensions	
Footprint	3528
L	3.5mm +/-0.2mm
W	2.8mm +/-0.2mm
Н	1.9mm +/-0.2mm
Т	0.13mm REF
S	0.8mm +0.1/-0.3mm
F	2.2mm +/-0.1mm
Α	1.9mm MIN
В	0.4mm +/-0.15mm
E	2.2mm REF
G	1.8mm REF
P	0.5mm REF
R	1mm REF
X	0.1mm +/-0.1mm REF

Specifications	
Capacitance	6.8 uF
Capacitance Tolerance	20%
Voltage DC	16 VDC (85C), 10.72 VDC (125C)
Temperature Range	-55/+125°C
Rated Temperature	85°C
Dissipation Factor	6% 120Hz 25C
Failure Rate	N/A
ESR	1200 mOhms (100kHz 25C)
Ripple Current	266 mA (rms, 100kHz 25C), 239.4 mA (rms, 85C), 106.4 mA (rms, 125C)
Leakage Current	1.1 uA (5min 25°C)

Packaging Specifications	
Packaging	T&R, 178mm
Packaging Quantity	2000

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